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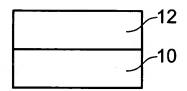
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Method of Forming Relaxed SiGe Layer Serial No.: 10/625,015 Jer-shen Maa, Douglas J. Tweet, and Sheng Teng Hsu

Fig. 1



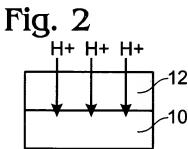


Fig. 3

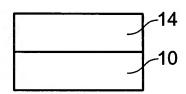


Fig. 4

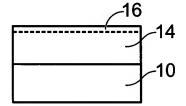


Fig. 5

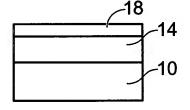
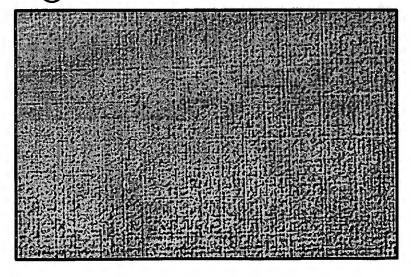


Fig. 6





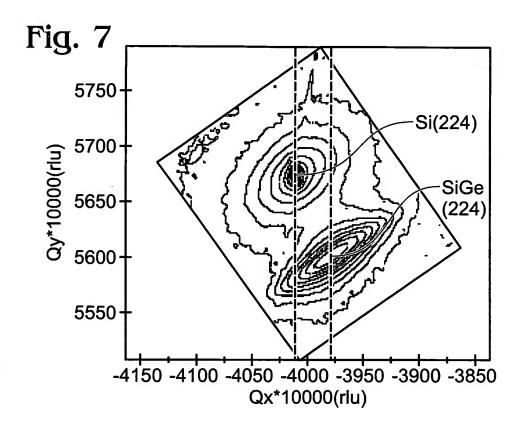
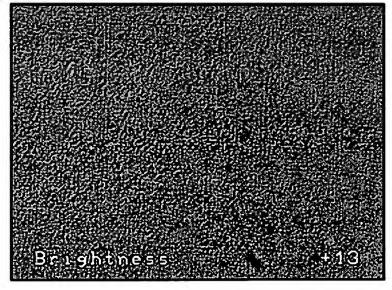


Fig. 8



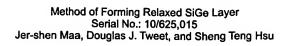
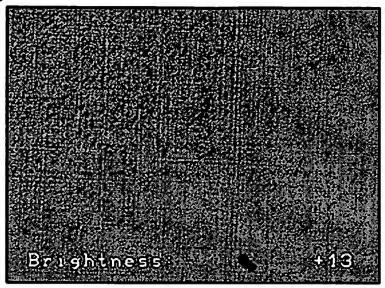
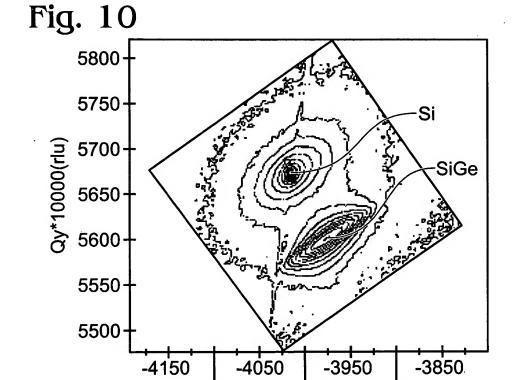




Fig. 9





-4100

-4000 -3900 Qx*10000(rlu)